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U.S. APPLICATION NUMBER NO. FIRST NAMED APPLICANT ATTY. DOCKET NO. 10/552.513 Yasushi Araki O90689 INTERNATIONAL APPLICATION NO. PCT/JP04/04935 23373 PRIORITY DATE I.A. FILING DATE SUGHRUE MION, PLLC 04/06/2005 04/07/2003 . 2100 PENNSYLVANIA AVENUE, N.W. 04101e12004 SUITE 800 MAY 3 0 2006 WASHINGTON, DC 20037 **CONFIRMATION NO. 2406** 371 ACCEPTANCE LETTER

Date Mailed: 05/26/2006

### NOTICE OF ACCEPTANCE OF APPLICATION UNDER 35 U.S.C 371 AND 37 CFR 1.495

The applicant is hereby advised that the United States Patent and Trademark Office in its capacity as a Designated / Elected Office (37 CFR 1.495), has determined that the above identified international application has met the requirements of 35 U.S.C. 371, and is ACCEPTED for national patentability examination in the United States Patent and Trademark Office.

The United States Application Number assigned to the application is shown above and the relevant dates are:

10/06/2005 •

10/06/2005

\*OC000000018906902\*

DATE OF RECEIPT OF 35 U.S.C. 371(c)(1), (c)(2) and (c)(4) REQUIREMENTS

DATE OF COMPLETION OF ALL 35 U.S.C. 371 REQUIREMENTS

A Filing Receipt (PTO-103X) will be issued for the present application in due course. THE DATE APPEARING ON THE FILING RECEIPT AS THE "FILING DATE" IS THE DATE ON WHICH THE LAST OF THE 35 U.S.C. 371 (c)(1), (c)(2) and (c)(4) REQUIREMENTS HAS BEEN RECEIVED IN THE OFFICE. THIS DATE IS SHOWN ABOVE. The filing date of the above identified application is the international filing date of the international application (Article 11(3) and 35 U.S.C. 363). Once the Filing Receipt has been received, send all correspondence to the Group Art Unit designated thereon.

The following items have been received:

- Copy of the International Application filed on 10/06/2005
- Copy of the International Search Report filed on 10/06/2005
- Preliminary Amendments filed on 10/06/2005
- Information Disclosure Statements filed on 10/06/2005
- Oath or Declaration filed on 10/06/2005
- Request for Immediate Examination filed on 10/06/2005
- Copy of references cited in ISR filed on 10/06/2005
- U.S. Basic National Fees filed on 10/06/2005
- Assignment filed on 10/06/2005
- Priority Documents filed on 10/06/2005
- Power of Attorney filed on 10/06/2005

- Specification filed on 10/06/2005
- Claims filed on 10/06/2005
- Abstracts filed on 10/06/2005
- Drawings filed on 10/06/2005

Applicant is reminded that any communications to the United States Patent and Trademark Office must be mailed to the address given in the heading and include the U.S. application no. shown above (37 CFR 1.5)

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PART 1 - ATTORNEY/APPLICANT COPY

FORM PCT/DO/EO/903 (371 Acceptance Notice)



#### PATENT APPLICATION

### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q90689

Yasushi ARAKI

Appln. No.: 10/552,513

Group Art Unit: 2812

Confirmation No.: 2406

Examiner: Not yet assigned

Filed: October 6, 2005

For:

CRYSTALLINE-SI-LAYER-BEARING SUBSTRATE AND ITS PRODUCTION METHOD,

AND CRYSTALLINE SI DEVICE

# REQUEST FOR CORRECTED NOTICE OF ACCEPTANCE OF APPLICATION UNDER 35 U.S.C. 371 AND 37 CFR 1.495

**ATTN:** Office of Initial Patent Examination

Filing Receipt Correction

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Sir:

We enclose a copy of the Official Filing Receipt for the above-identified application and request the following correction:

#### I.A. FILING DATE

04/06/2005 04/06/2004

Verification for the requested correction is indicated on the enclosed copy of the Publication (first page of the International Application) which was filed on April 6, 2004.

Respectfully submitted,

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WASHINGTON OFFICE

23373

CUSTOMER NUMBER

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For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

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